NSN 5961-01-110-4395

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-110-4395

view Offiline at https://aerobasegroup.com/histi/0501-01-110-4050
Inclosure Material:
Plastic
Overall Length:
Between 0.170 inches and 0.210 inches
Terminal Length:
0.500 inches
Overall Height:
Between 0.125 inches and 0.165 inches
Overall Width:
Between 0.175 inches and 0.205 inches
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-92
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
60.0 collector to base voltage, dc and 40.0 collector to emitter voltage, dc and 6.0 emitter to base voltage, dc
Current Rating Per Characteristic:
200.00 milliamperes source cutoff current
Power Rating Per Characteristic:
350.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-s-19500/529 government specification
Shelf Life:
N/a
Unit Of Measure:

No

Demilitarization:

NSN 5961-01-110-4395 Transistor - Page 2 of 2



Fiig:

A110a0